



June 1989

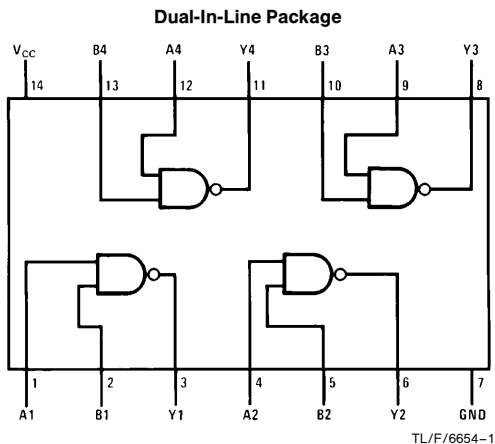
# DM54L00

## Quad 2-Input NAND Gates

### General Description

This device contains four independent gates each of which performs the logic NAND function.

### Connection Diagram



Order Number DM54L00J or DM54L00W  
See NS Package Number J14A or W14B

### Function Table

$Y = \overline{AB}$

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

H = High Logic Level  
L = Low Logic Level

DM54L00 Quad 2-Input NAND Gates

**Absolute Maximum Ratings** (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	8V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM57L	−55°C to +125°C
Storage Temperature Range	−65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

**Recommended Operating Conditions**

Symbol	Parameter	DM54L00			Units
		Min	Nom	Max	
V <sub>CC</sub>	Supply Voltage	4.5	5	5.5	V
V <sub>IH</sub>	High Level Input Voltage	2			V
V <sub>IL</sub>	Low Level Input Voltage			0.7	V
I <sub>OH</sub>	High Level Output Current			−0.2	mA
I <sub>OL</sub>	Low Level Output Current			2	mA
T <sub>A</sub>	Free Air Operating Temperature	−55		125	°C

**Electrical Characteristics** over recommended operating free air temperature (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
V <sub>OH</sub>	High Level Output Voltage	V <sub>CC</sub> = Min, I <sub>OH</sub> = Max V <sub>IL</sub> = Max	2.4	3.3		V
V <sub>OL</sub>	Low Level Output Voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = Max V <sub>IH</sub> = Min		0.15	0.3	V
I <sub>I</sub>	Input Current @ Max Input Voltage	V <sub>CC</sub> = Max, V <sub>I</sub> = 5.5V			0.1	mA
I <sub>IH</sub>	High Level Input Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 2.4V			10	μA
I <sub>IL</sub>	Low Level Input Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 0.3V			−0.18	mA
I <sub>OS</sub>	Short Circuit Output Current	V <sub>CC</sub> = Max (Note 2)	−3		−15	mA
I <sub>CCH</sub>	Supply Current with Outputs High	V <sub>CC</sub> = Max		0.44	0.8	mA
I <sub>CCL</sub>	Supply Current with Outputs Low	V <sub>CC</sub> = Max		1.16	2.04	mA

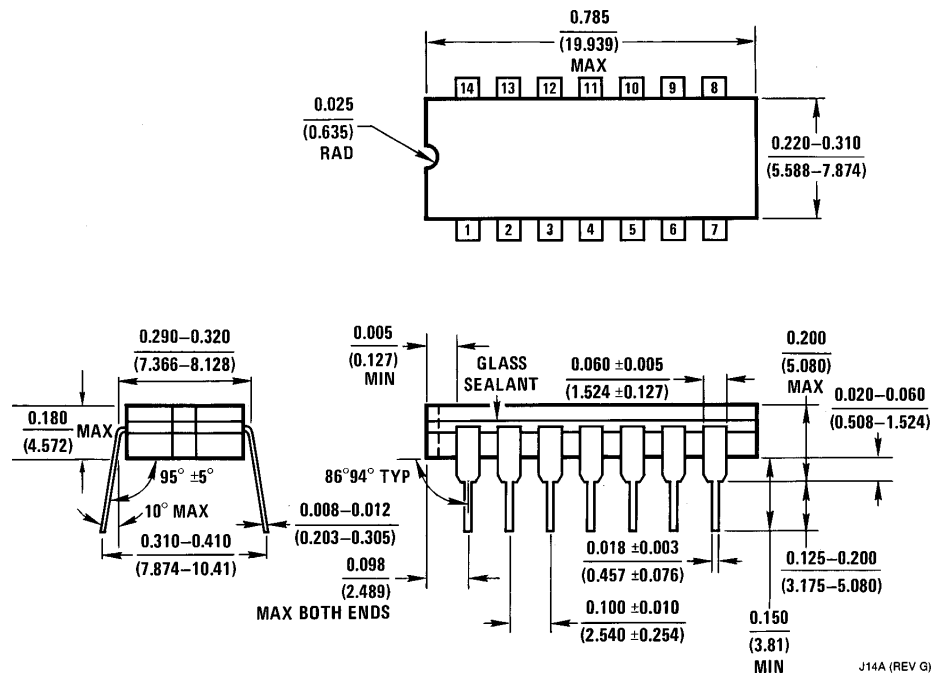
Note 1: All typicals are at V<sub>CC</sub> = 5V, T<sub>A</sub> = 25°C.

Note 2: Not more than one should be shorted at a time.

**Switching Characteristics** at V<sub>CC</sub> = 5V and T<sub>A</sub> = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	Conditions	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay Low to High Level Output	R <sub>L</sub> = 4 kΩ C <sub>L</sub> = 50 pF		60	ns
t <sub>PHL</sub>	Propagation Delay High to Low Level Output			60	ns

**Physical Dimensions** inches (millimeters)

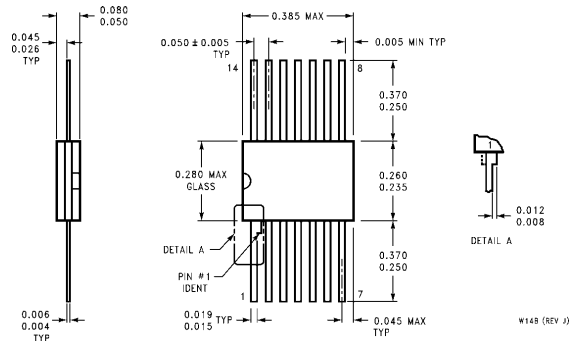


14-Lead Ceramic Dual-In-Line Package (J)  
Order Number DM54L00J  
NS Package Number J14A

J14A (REV G)

DM54L00 Quad 2-Input NAND Gates

Physical Dimensions inches (millimeters) (Continued)




14-Lead Ceramic Flat Package (W)  
Order Number DM54L00W  
NS Package Number W14B

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